RENESAS HD74LV1GT66A

Analog Switch

REJ03D0121-0800 Rev.8.00 Mar 21, 2008

Description

The HD74LV1GT66A has an analog switch in a 5 pin package. Switch section has its enable input control (C). Highlevel voltage applied to C turns on the switch section. Applications include signal gating, chopping, modulation, or demodulation (modem), and signal multiplexing for analog to digital and digital to analog conversion systems. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

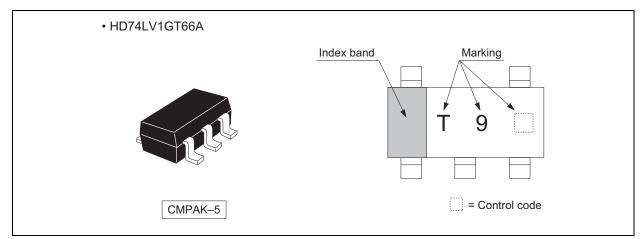
Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Control input is TTL compatible input level. Supply voltage range : 3.0 to 5.5 V Operating temperature range : -40 to +85°C
- Control inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- Control inputs have hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1GT66ACME	CMPAK–5 pin	PTSP0005ZC-A (CMPAK-5V)	СМ	E (3000 pcs/reel)
HD74LV1GT66AVSE	VSON–5 pin	PUSN0005KA-A (TNP-5DV)	VS	E (3000 pcs/reel)

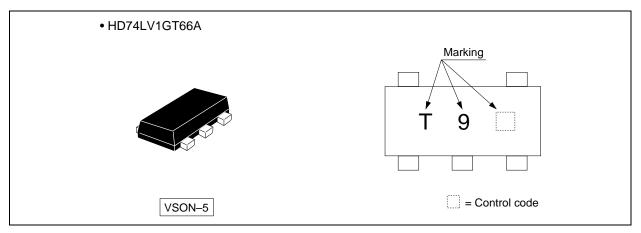
Note: Please consult the sales office for the above package availability.

Outline and Article Indication



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Outline and Article Indication



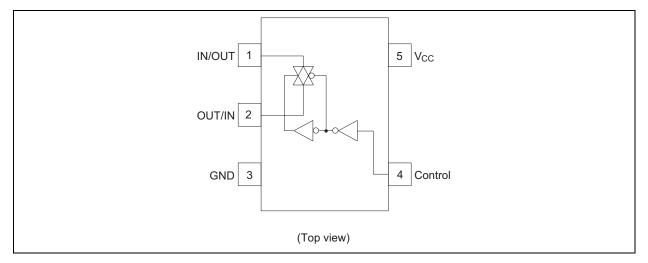
Function Table

Control	Switch				
L	OFF				
Н	ON				

H : High level

L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range *1	VI	-0.5 to 7.0	V	
Output voltage range *1, 2	Vo	–0.5 to V _{CC} + 0.5	V	Output : H or L
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	loк	±50	mA	$V_0 < 0$ or $V_0 > V_{CC}$
Continuous output current	lo	±25	mA	$V_0 = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25° C (in still air) ^{*3}	PT	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	3.0	5.5	V	
Input voltage range	VI	0	5.5	V	
Input / output voltage range	V _{I/O}	0	V _{cc}	V	
Input transition rise or fall rate	Δt / Δv	0	100	ns / V	V_{CC} = 3.0 to 3.6 V
	$\Delta t / \Delta v$	0	20	115 / V	V_{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating control inputs must be held high or low.

Electrical Characteristics

ltom	Cumb al	V 00	Т	a = 25°	С	T _a = −40 to 85°C			Unit	Test Conditions	
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Тур	Max	Unit		
	VIH	3.0 to 3.6	_	—		1.5	—				
Input voltage	VIH	4.5 to 5.5	_	—	—	2.0	—	—	v	Control input only	
input voltage	VIL	3.0 to 3.6	_	_	—	—	—	0.6	v		
	VIL	4.5 to 5.5	_	_	—	—	—	0.8			
Hysteresis	V _H	3.3	—	—	_	—	0.10	_	V	$V_{T}^{+} - V_{T}^{-}$	
voltage	∨н	5.0	—	—	_	—	0.15	_	v	$v_{\rm T} - v_{\rm T}$	
On-state switch		3.0	—	50	150	—	—	190		$V_{IN} = V_{CC} \text{ or } GND$	
resistance	R _{ON}	4.5	—	40	75		-	100	Ω	$V_{C} = V_{IH}$ $I_{T} = 1 \text{ mA}$	
Peak on		3.0	_	100	180	_		225		$V_{IN} = V_{CC}$ to GND	
resistance	R _{ON (P)}	4.5	_	50	100	_	_	125	Ω	$V_{C} = V_{IH}$ $I_{T} = 1 \text{ mA}$	
Off-state switch leakage current	I _{s (OFF)}	5.5	_	_	±0.1	_	_	±1.0	μΑ	$V_{IN} = V_{CC}, V_{OUT} = GND$ or $V_{IN} = GND$, $V_0 = V_{CC}, V_C = V_{IL}$	
On-state switch leakage current	I _{s (ON)}	5.5		_	±0.1	_	_	±1.0	μA	$V_{IN} = V_{CC}$ or GND $V_C = V_{IH}$	
Input current	I _{IN}	0 to 5.5	—	—	±0.1	—	—	±1.0	μΑ	$V_{IN} = 5.5 \text{ V or GND}$	
Quiescent	I _{CC}	5.5	—	—	_	—	—	10	μΑ	$V_{IN} = V_{CC} \text{ or } GND$	
supply current	ΔI_{CC}	5.5	—	_	—		—	1.5	mA	V _{IN} = 3.4 V	
Control input capacitance	C _{IC}	_	—	3.5	_		_	_	pF		
Switch terminal capacitance	C _{IN/OUT}	_	_	4.0	_	_	_	_	pF		
Feed through capacitance	C _{IN-OUT}	—		0.5	—	_	—	—	pF		

Switching Characteristics

• $V_{CC} = 3.3 \pm 0.3 V$

ltem Symbol		Ta = 25°C			Ta = -40 to 85°C		Unit	Test	FROM	то
item	Symbol	Min	Тур	Max	Min	Max	Onic	Conditions	(Input)	(Output)
Propagation	t _{PLH}	—	1.5	6.0		10.0	ns	C∟ = 15 pF	IN/OUT	OUT/IN
delay time	t _{PHL}	_	4.0	9.0	_	12.0	115	C∟ = 50 pF	or OUT/IN	or IN/OUT
Enable time	t _{ZH}	—	4.0	11.0	_	15.0	20	C _L = 15 pF	С	IN/OUT
	t _{ZL}	_	6.0	18.0	_	22.0	ns	C _L = 50 pF	C	or OUT/IN
Disable time	t _{HZ}	_	5.0	11.0	_	15.0	20	C _L = 15 pF	С	IN/OUT
	t _{LZ}	_	8.0	18.0	_	22.0	ns	C _L = 50 pF	0	or OUT/IN

• $V_{CC} = 5.0 \pm 0.5 V$

ltem Symbol		Ta = 25°C			Ta = -40) to 85°C	Unit	Test	FROM	то
nem	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	—	1.0	4.0	—	7.0	ne	C _L = 15 pF	IN/OUT	OUT/IN
delay time	t _{PHL}	—	3.0	6.0	—	8.0	ns	$C_L = 50 \text{ pF}$	or OUT/IN	or IN/OUT
Enable time	t _{ZH}	_	3.0	7.0	—	10.0	20	C _L = 15 pF	С	IN/OUT
	t _{ZL}	_	5.0	12.0	—	16.0	ns	C _L = 50 pF	C	or OUT/IN
Disable time	t _{HZ}	_	4.0	7.0	—	10.0	20	C _L = 15 pF	С	IN/OUT
	t _{LZ}	—	6.0	12.0	—	16.0	ns	C _L = 50 pF	0	or OUT/IN

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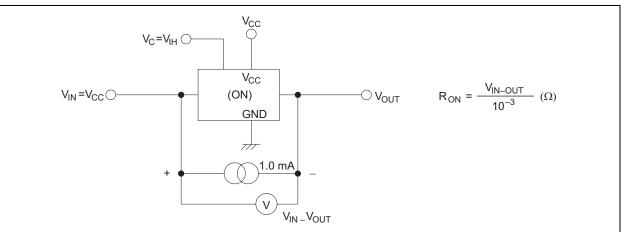
Operating Characteristics

• $C_L = 50 \text{ pF}$

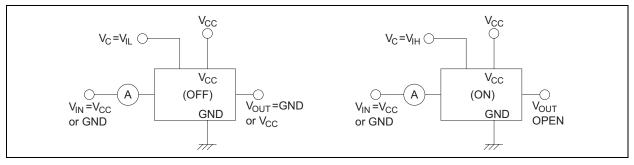
Item	m Symbol		Symbol	Symbol	Symbol	Symbol	Symbol	Symbol	Symbol	V _{cc} (V)		Ta = 25°C	;	Unit	Test Conditions
item	Symbol	VCC(V)	Min	Тур	Max	Unit	Test conditions								
Power dissipation capacitance	C _{PD}	5.0		4.0	_	pF	f = 10 MHz								

Test Circuit

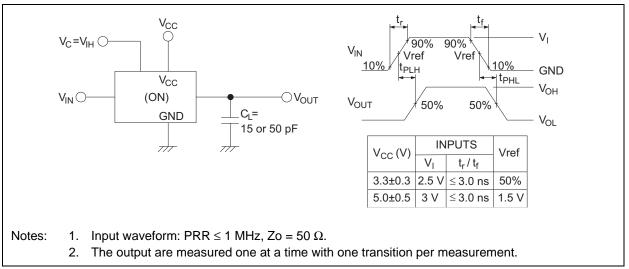
• R_{ON}



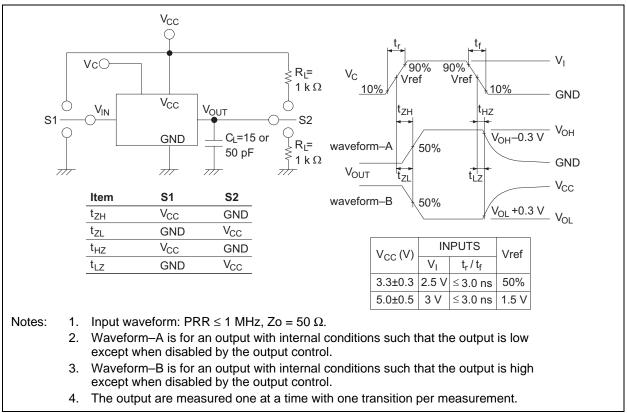
• $I_{S}(off), I_{S}(on)$



• t_{PLH}, t_{PHL}

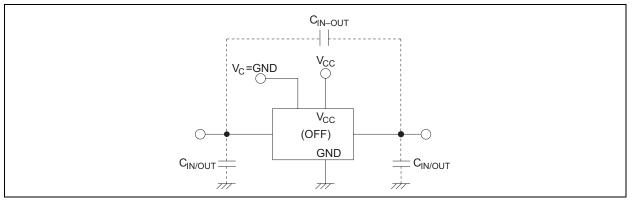


• $t_{ZH}, t_{ZL} / t_{HZ}, t_{LZ}$

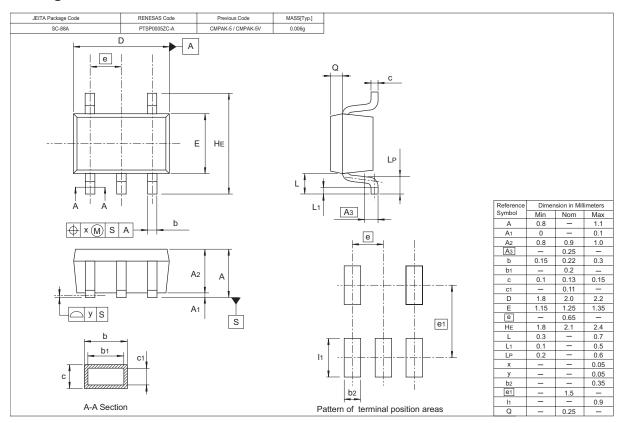


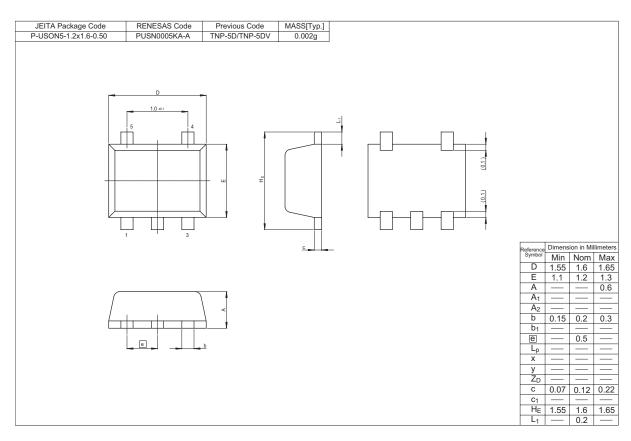
HD74LV1GT66A

• C_{IN/OUT}, C_{IN-OUT}



Package Dimensions





REJ03D0121-0800 Rev.8.00, Mar 21, 2008 Page 8 of 8 RENESAS

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http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

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